



Bipolar PNP Bare Die – BTP075

Part Description

The BTP075 is a silicon BJT transistor available in bare die form and well suited for use in High Voltage Driver applications.

Key Parameters:

- VCBO = -400V
- VCEO = -400V
- VEBO = -7V
- hFE = 70-200 @ VCE = -10V, IC = -0.02A
- VCE(Sat) = -0.5V @ IC = -0.05A, IB = -5mA
- fT = 50 MHz @ VCE = -10V, IE = 0A
- COBO = 7pF @ VCB = -20V

Features

Die Size (Unseen)

720µm X 720µm, 28 Mils X 28 Mils

This is a shortform datasheet only

For the full datasheet

Please contact sales@siliconsupplies.com

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